

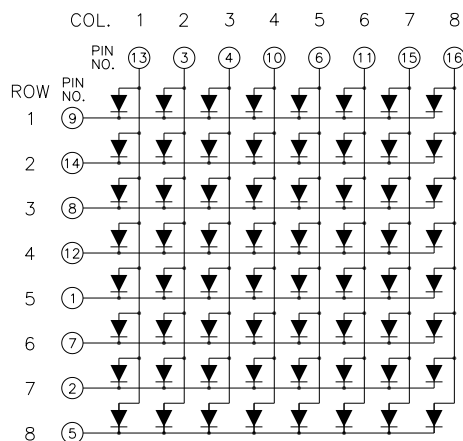
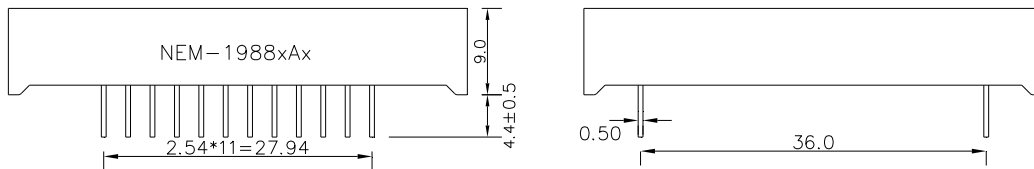
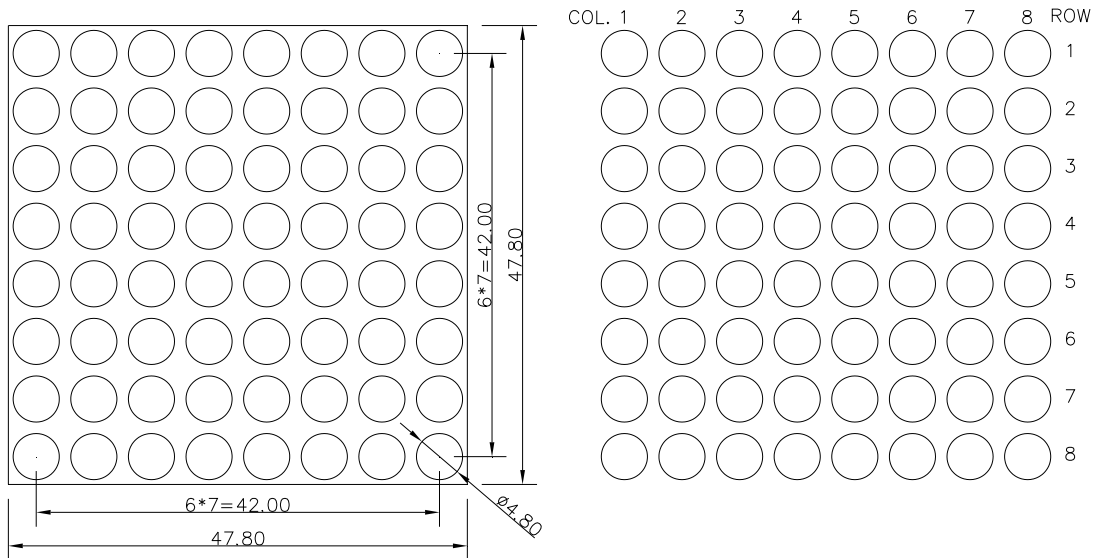
Features:

- Large emitting dot 4.8 mm diameter.
- Low current operation.
- Easy mounting on P.C. boards or sockets.
- Wide viewing angle.
- Solid state reliability.
- Mechanically rugged.
- Pb free.
- RoHS compliant.

Descriptions:

- The NEM-1988xAx series is a large emitting area (4.8 mm diameter) LED sources configured in a 64 dot 8*8 matrix array.
- These devices are made with black surface and white segments.
- The Yellow source color devices are made with AlGaInP Yellow Light Emitting Diode

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters(inches),Tolerance is ± 0.25 (0.01") unless otherwise noted.
2. Specifications are subject to change without notice.

Absolute maximum ratings (Ta = 25°C)

Part No.: NEM-19881AY-11

Parameter	Symbol		Value		Unit
			Min.	Max.	
Reverse Voltage	V _R	----	----	5	V
Forward Current	I _F	----	----	25	mA
Power Dissipation	P _d	----	----	60	mW
Pulse Current	I _{peak}	Duty=0.1mS, 1kHz	----	80	mA
Operating Temperature	T _{opr}	----	-25	+85	°C
Storage Temperature	T _{str}	----	-30	+85	°C
Solder Temperature	T _{sol}	1/16inch below Seating plane	260/3		°C/s

Electrical and optical characteristics (Ta = 25°C)

Parameter	Symbol	Test Condition	Values			Unit
			Min.	Typ.	Max.	
Forward Voltage	V _F	I _F =20mA	----	1.9	2.3	V
Reverse Current	I _R	V _R =5V	----	----	30	μA
Dominate Wavelength	λ _d	I _F =20mA	----	586	----	nm
Peak Wavelength	λ _p	I _F =20mA	----	583	----	nm
Spectral Line half-width	Δλ	I _F =20mA	----	20	----	nm
Luminous Intensity	I _v	I _F =10mA	----	5000	----	ucd

Typical electrical/optical characteristic curves:

